

VO₂(B) conversion to VO₂(A) and VO₂(M) and their oxidation resistance and optical switching properties

YIFU ZHANG*

School of Chemistry, Dalian University of Technology, Dalian 116024, PR China

Vanadium dioxide VO₂ has been paid in recent years increasing attention because of its various applications, however, its oxidation resistance properties in air atmosphere have rarely been reported. Herein, VO₂(B) nanobelts were transformed into VO₂(A) and VO₂(M) nanobelts by hydrothermal route and calcination treatment, respectively. Then, we comparatively studied the oxidation resistance properties of VO₂(B), VO₂(A) and VO₂(M) nanobelts in air atmosphere by thermo-gravimetric analysis and differential thermal analysis (TGA/DTA). It was found that the nanobelts had good thermal stability and oxidation resistance below 341 °C, 408 °C and 465 °C in air, respectively, indicating that they were stable in air at room temperature. The fierce oxidation of the nanobelts occurred at 426, 507 and 645 °C, respectively. The results showed that the VO₂(M) nanobelts had the best thermal stability and oxidation resistance among the others. Furthermore, the phase transition temperatures and optical switching properties of VO₂(A) and VO₂(M) were studied by differential scanning calorimetry (DSC) and variable-temperature infrared spectra. It was found that the VO₂(A) and VO₂(M) nanobelts had outstanding thermochromic character and optical switching properties.

Keywords: VO₂ polymorphs; thermal properties; oxidation resistance; phase transition; optical properties

© Wroclaw University of Technology.

1. Introduction

Over the past decades, numerous efforts have been employed in vanadium oxides and their related compounds as functional materials because of their layered structures, unique chemical and physical properties, which make them highly desired in a wide range of promising potential applications such as catalysts, cathode materials for reversible lithium batteries, gas sensors, intelligent thermochromic windows, electrical and optical devices, laser shield and so on [1–14]. As is well known, vanadium has abundant oxidation states (0 to +5), which usually correspond to a variety of binary oxides with the general formula VO_{2+x} (−0.5 ≤ x ≤ 0.5) [15, 16], such as V₂O₅, VO₂, V₂O₃, V₃O₇, V₄O₉, V₆O₁₃, etc. In the family of vanadium oxides, vanadium dioxide (VO₂) is a representative binary compound with different polymorphs, including VO₂(M), VO₂(R), VO₂(B),

VO₂(A), VO₂(C), VO₂(D), etc. Among the VO₂ polymorphs, VO₂(B), VO₂(M/R) and VO₂(A) have been paid much attention in the past decades, and their crystallography data [17–20] are listed in Table 1.

VO₂(B) has attracted a great interest as a promising cathode material for Li-ion batteries, not only due to its proper electrode potential, but also its tunnel structure, through which Li-ions can make intercalation and de-intercalation in a reversible Li-ion battery [13, 21, 22]. Besides, VO₂(B) is usually used as a precursor to be transformed to VO₂(M/R) [22]. VO₂(M) shows a fully reversible first-order metal-to-insulator transition (MIT) with the phase transition temperature (T_c) at about 68 °C, accompanied by a crystallographic transition between a low temperature monoclinic phase (M) and a high temperature tetragonal phase (R) [23–27]. On warming, due to this transition, drastic changes occur in both electrical and optical properties below and above T_c. For instance, the infrared transmission characteristics of VO₂(M)

*E-mail: yfzhang@dlut.edu.cn

Table 1. The crystallography data of some important types of VO₂ polymorph.

Phase	T _c [°C]*	Cs*	Sg*	a [Å]	b [Å]	c [Å]	β (°)	Ref.
VO ₂ (B)	—	Monoclinic	C2/m	12.03	3.693	6.420	106.6	[17]
VO ₂ (M)	68	Monoclinic	P2 ₁ /c	5.743	4.157	5.375	122.6	[18]
VO ₂ (R)	68	Tetragonal	P4 ₂ /mm	4.530	4.530	2.869	—	[19]
VO ₂ (A _L)	162	Tetragonal	P4/ncc	8.440	8.440	7.666	—	[20]
VO ₂ (A _H)	162	Tetragonal	I4/m	8.476	8.476	3.824	—	[20]

*T_c: phase transition temperature; Cs: Crystal system; Sg: Space group.

dramatically change over the phase transition and the change in electrical resistivity is of the order of 10⁵ [23, 28]. These characteristics make VO₂(M) to be considered as a candidate for applications in smart window coatings, optical switching devices, intelligent energy conserving windows, electrical devices, laser protection, etc. [5, 6, 29–32]. Recently, an increasing attention has been paid to tetragonal VO₂(A) (space group P4₂/ncm) [26, 33, 34], because it shows a metal-semiconductor transition with the phase transition temperature (T_c) at 162 °C, accompanied by a crystallographic transition between a low temperature phase (LTP, P4/ncc, 130 °C below 162 °C) and a high temperature phase (HTP, I4/m, 87 °C above 162 °C). In the past decades, the synthesis, characterization and properties of VO₂(B), VO₂(M) and VO₂(A) have been extensively studied, however, the oxidation resistance properties of VO₂(B), VO₂(A) and VO₂(M) in air atmosphere have rarely been reported.

In this contribution, we first synthesized VO₂(B), VO₂(A) and VO₂(M) nanobelts and then studied their thermal behavior in air atmosphere. It was found that the as-obtained VO₂(B), VO₂(A) and VO₂(M) nanobelts had good thermal stability and oxidation resistance in air below 341 °C, 408 °C and 465 °C, respectively, indicating that the VO₂(M) nanobelts had the best thermal stability and oxidation resistance. Furthermore, the phase transition temperatures and optical switching properties of VO₂(A) and VO₂(M) were studied, and it was found that the VO₂(A) and VO₂(M) had outstanding thermochromic characteristics and optical switching properties.

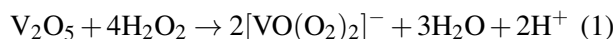
2. Experimental

2.1. Materials

Vanadium pentoxide (V₂O₅), hydrogen peroxide (H₂O₂, 30 wt.%) and ethanol (CH₃CH₂OH) with analytical grade were purchased from Sinopharm Chemical Reagent Co., Ltd., and used without any further purification.

2.2. Synthesis of VO₂ (B) nanobelts

The synthesis of VO₂(B) nanobelts was based on our previous reports [22, 35] and slightly modified. In a typical synthesis, 0.455 g of commercial V₂O₅ was dispersed in 31 mL of redistilled water with magnetic stirring. Then 2 mL of H₂O₂ and 2 mL of ethanol were successively added into the solution, which was still stirred for 1 h at room temperature to obtain a brown liquid ([VO(OH)₂]⁺ solution), as shown in equation 1:



After the solution achieved good homogeneity, the mixture was transferred into a 50 mL Teflon-lined stainless steel autoclave, then sealed and maintained at 180 °C for 48 h. When the reaction was finished, the blue-black precipitates were filtered off, washed with distilled water and anhydrous alcohol several times to remove any possible residues, and dried in vacuum at 75 °C for future applications.

2.3. Synthesis of VO₂(A) nanobelts transformed from VO₂(B) nanobelts

In a typical synthetic route for transforming VO₂(B) to VO₂(A), 0.50 g of the VO₂(B) nanobelts

was dispersed into 40 mL of deionized water with magnetic stirring. The mixed solution was transferred into a 60 mL stainless steel autoclave after the solution became suspension. The autoclave was sealed and maintained at 280 °C for 48 h and then cooled to room temperature naturally. The products were filtered off, washed with distilled water and absolute ethanol several times to remove any possible residues, and dried in vacuum at 75 °C.

2.4. Synthesis of VO₂(M) nanobelts transformed from VO₂(B) nanobelts

In a typical transformation from VO₂(B) to VO₂(M), about 0.40 g of the VO₂(B) nanobelts were heated in a tube furnace with 5 °C/min heating rate under a high purity Ar (99.999 %) atmosphere at 700 °C for 2 h, and cooled to room temperature in the Ar flow to prevent the oxidation of VO₂(M).

2.5. Characterization

X-ray powder diffraction (XRD) study was carried out on D8 X-ray diffractometer equipment with Cu *K*α radiation, $\lambda = 1.54060$ Å. The data were collected between 5° and 70° with a scan speed of 4°/min. The morphology and dimensions of the products were observed by the transmission electron microscopy (TEM, JEM-2100). The sample was dispersed in absolute ethanol and was ultrasonicated before TEM. Thermogravimetric analysis and differential thermal analysis (TGA/DTA) were performed on SETSYS-1750 (AETARAM Instruments). About 10 mg of the sample was heated in an Al₂O₃ crucible in air atmosphere from ambient temperature to 700 °C at a constant rise of temperature (10 °C/min). The phase transition temperature (*T*_c) of VO₂(A) and VO₂(M) was measured by differential scanning calorimetry (DSC, DSC822°, METTLER TOLEDO) with 5 °C/min heating rate. Optical properties of VO₂(A) and VO₂(M) were tested by variable-temperature Fourier transform infrared spectroscopy (IR, NICOLET 5700) with an adapted heating controlled cell. Variable-temperature IR patterns of the solid samples were measured using KBr pellet technique from 4000

to 400 cm⁻¹ with a resolution of 4 cm⁻¹. About 1 wt.% of the samples and 99 wt.% of KBr were mixed homogeneously, and then the mixture was pressed into a pellet.

3. Results and discussion

3.1. Characterization of VO₂(B), VO₂(A) and VO₂(M) nanobelts

Fig. 1 depicts the typical XRD patterns of the as-prepared VO₂(B). All the diffraction peaks from Fig. 1b can readily be indexed to the monoclinic crystalline phase (space group C2/m) of VO₂(B) in agreement with the literature values (JCPDS Card No. 65-7960) [17], whose plots are shown in Fig. 1a. No impurity phases, such as V₂O₅, V₃O₇, V₆O₁₃, VO₂(M), VO₂(A) and V₂O₃, were detected, indicating high purity of the as-obtained VO₂(B).

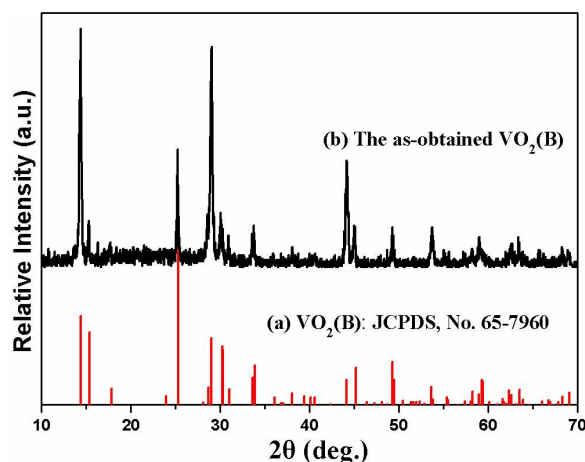


Fig. 1. XRD patterns of the as-obtained VO₂(B) nanobelts.

After hydrothermal treatment of VO₂(B) at 280 °C for 48 h, the XRD of the product has been measured and is shown in Fig. 2. It can be observed from Fig. 2 that all the diffraction peaks can readily be indexed to the tetragonal crystalline phase (space group: P42/ncm, No. 138) of VO₂(A) (JCPDS Card No. 42-0876) [36], indicating that the VO₂(A) was successfully transformed from VO₂(B). The as-prepared VO₂(A) is of high purity what can be inferred by comparing Fig. 2a

and Fig. 2b. After calcination, $\text{VO}_2(\text{B})$ was transformed into $\text{VO}_2(\text{M})$, as shown in Fig. 3. All the diffraction peaks in Fig. 3b can readily be indexed to the monoclinic crystalline phase (space group: $\text{P}21/\text{c}$, No. 14) of $\text{VO}_2(\text{M})$ (JCPDS Card No. 72-0514) [18] and the as-prepared $\text{VO}_2(\text{M})$ is of high purity what can be stated by comparing Fig. 3a and Fig. 3b. Therefore, it can be said that $\text{VO}_2(\text{B})$, $\text{VO}_2(\text{A})$ and $\text{VO}_2(\text{M})$ were successfully prepared.

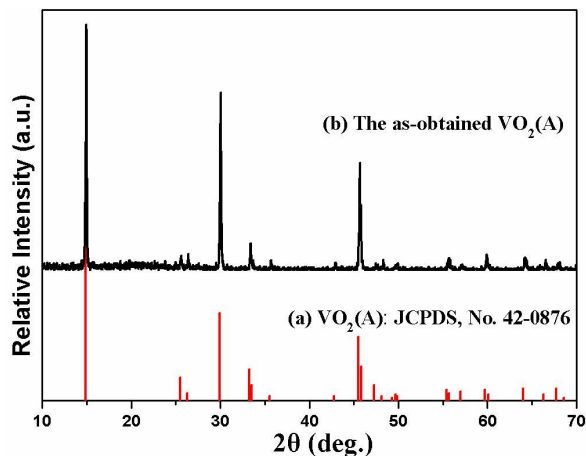


Fig. 2. XRD patterns of the as-obtained $\text{VO}_2(\text{A})$ transformed from $\text{VO}_2(\text{B})$ nanobelts by hydrothermal treatment at 280 °C for 48 h.

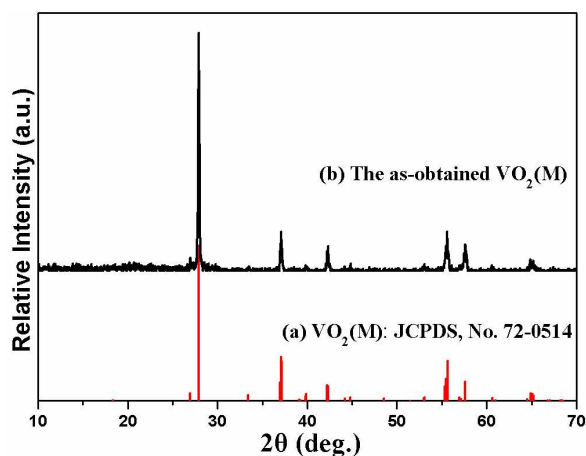


Fig. 3. XRD patterns of the as-obtained $\text{VO}_2(\text{M})$ transformed from $\text{VO}_2(\text{B})$ nanobelts by heating treatment at 700 °C for 2 h.

Fig. 4 shows the typical TEM images of the as-prepared $\text{VO}_2(\text{B})$, $\text{VO}_2(\text{A})$ and $\text{VO}_2(\text{M})$ nanobelts,

which reveal that the as-obtained $\text{VO}_2(\text{B})$, $\text{VO}_2(\text{A})$ and $\text{VO}_2(\text{M})$ have similar morphology. The TEM images indicate that all of the as-obtained $\text{VO}_2(\text{B})$, $\text{VO}_2(\text{A})$ and $\text{VO}_2(\text{M})$ consist of a large number of 1D nanobelts with the length in the range of several to tens of micrometers and width ranging from 80 to 200 nm.

3.2. The oxidation resistance properties

In the past decades, $\text{VO}_2(\text{B})$, $\text{VO}_2(\text{A})$ and $\text{VO}_2(\text{M})$ nanobelts have been extensively studied, however, their oxidation resistance properties have not been reported in the literature. Therefore, in this contribution, the oxidation resistance properties of $\text{VO}_2(\text{B})$, $\text{VO}_2(\text{A})$ and $\text{VO}_2(\text{M})$ nanobelts were investigated by TGA/DTA with the flowing air, as shown in Fig. 5 and Fig. 6. Fig. 5 shows the TG curves of the as-obtained $\text{VO}_2(\text{B})$, $\text{VO}_2(\text{A})$ and $\text{VO}_2(\text{M})$ nanobelts in air atmosphere, which reveal that their oxidation process by O_2 starts at 341, 408 and 465 °C, respectively. The oxidation process of $\text{VO}_2(\text{B})$, $\text{VO}_2(\text{A})$ and $\text{VO}_2(\text{M})$ is finished at 472, 594 and 675 °C, respectively. The above results suggest that the $\text{VO}_2(\text{M})$ nanobelts have the best thermal stability and oxidation resistance. After the TGA/DTA test, a yellow powder was obtained, whose color is the same as that of V_2O_5 , indicating that VO_2 is oxidized to V_2O_5 .

As shown in Fig. 5, before beginning of VO_2 oxidation, the weight loss was not zero, which was caused by the loss of water absorbed on its surface. The weight loss of $\text{VO}_2(\text{B})$ is the largest while that of $\text{VO}_2(\text{M})$ is the least. The reason could be that $\text{VO}_2(\text{B})$ was directly prepared by a hydrothermal route and $\text{VO}_2(\text{M})$ was obtained by heating $\text{VO}_2(\text{B})$ at 700 °C, which could reduce the absorbed water. The weight loss of $\text{VO}_2(\text{B})$, $\text{VO}_2(\text{A})$ and $\text{VO}_2(\text{M})$ nanobelts in their oxidative process is 8.29, 9.01 and 9.54 %, respectively. The weight loss values of $\text{VO}_2(\text{B})$, $\text{VO}_2(\text{A})$ and $\text{VO}_2(\text{M})$ nanobelts correspond to the oxidation of the bulk VO_2 to V_2O_5 (9.64 %).

Fig. 6 shows the heat flow curves of the as-obtained $\text{VO}_2(\text{B})$, $\text{VO}_2(\text{A})$ and $\text{VO}_2(\text{M})$ nanobelts in air atmosphere, which suggests that the fierce oxidation of $\text{VO}_2(\text{B})$, $\text{VO}_2(\text{A})$ and $\text{VO}_2(\text{M})$ nanobelts

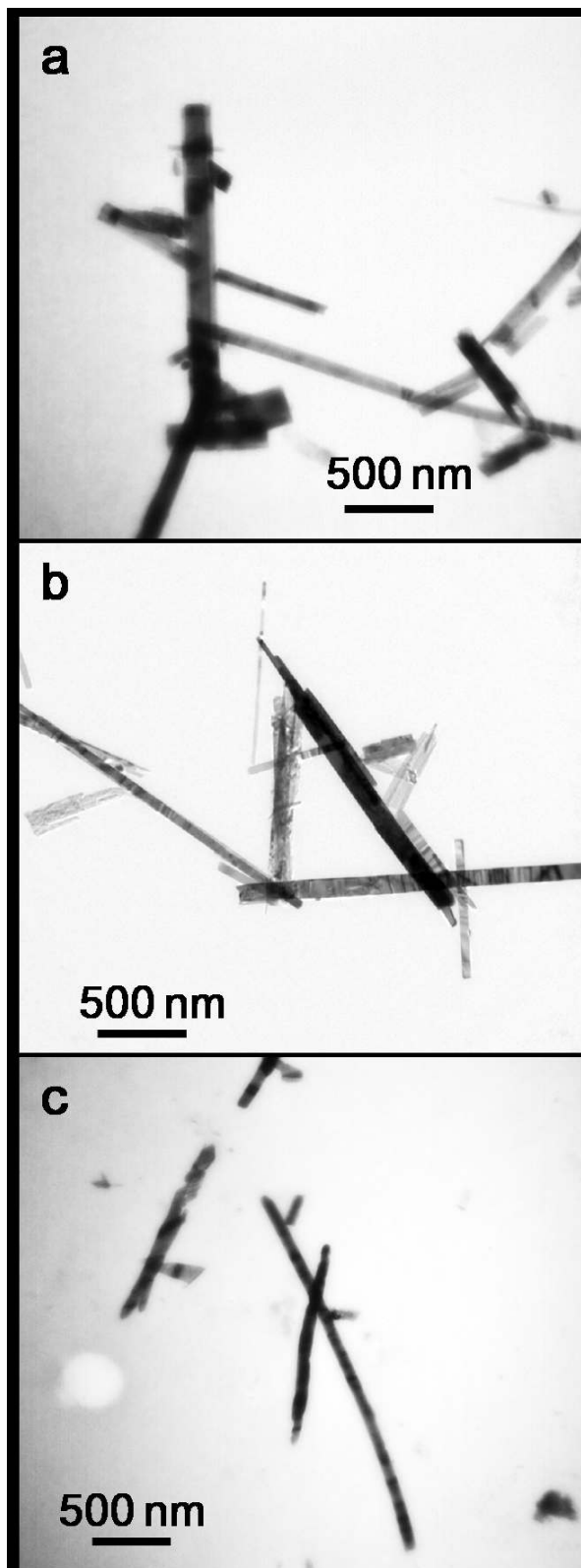


Fig. 4. TEM images of the as-obtained nanobelts: (a) VO₂(B), (b) VO₂(A) and (c) VO₂(M).

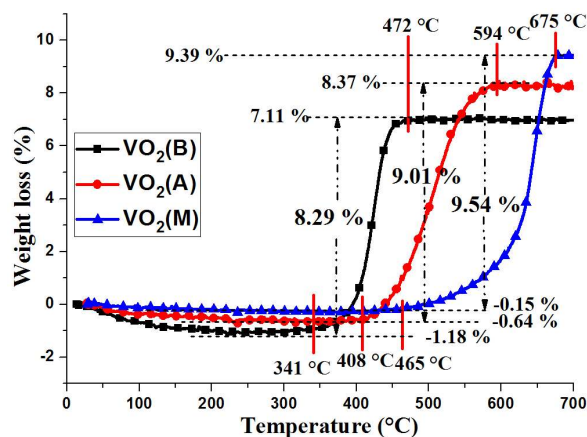


Fig. 5. TG curves of the as-obtained VO₂(B), VO₂(A) and VO₂(M) nanobelts in air atmosphere.

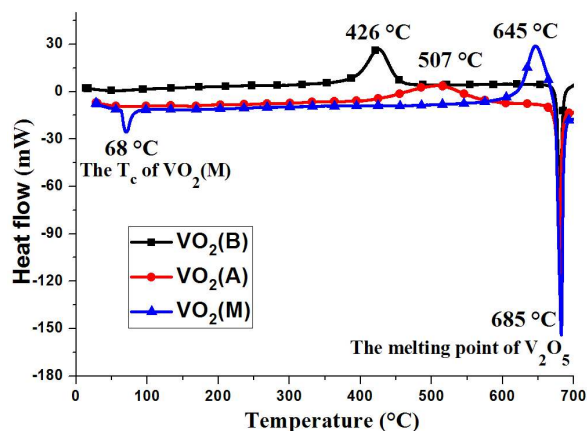


Fig. 6. Heat flow curves of the as-obtained VO₂(B), VO₂(A) and VO₂(M) nanobelts in air atmosphere.

occurs at 426, 507 and 645 °C, respectively. The sharp endothermic peak at about 685 °C is the melting point of V₂O₅, which further confirms that the oxidative product is V₂O₅. By the way, for VO₂(M) curve, a peak at 68 °C appears, which is the T_c of VO₂(M). Based on these results, it can be stated that the VO₂(B), VO₂(A) and VO₂(M) nanobelts have good thermal stability and oxidation resistance properties below 341, 408 and 465 °C in air atmosphere, respectively while the VO₂(M) nanobelts have the best thermal stability and oxidation resistance, which is beneficial for the application of VO₂(M) in air.

3.3. The phase transition and optical switching properties of VO₂(A) and VO₂(M) nanobelts

When the phase transition of VO₂(A) or VO₂(M) occurs, they exhibit a noticeable endothermic profile in the heating DSC curve, which corresponds to the phase transition of VO₂(A) or VO₂(M). Fig. 7 shows the typical DSC curves of VO₂(A) and VO₂(M). The T_c of VO₂(A) is about 162 °C, while for VO₂(M), the T_c is about 67 °C.

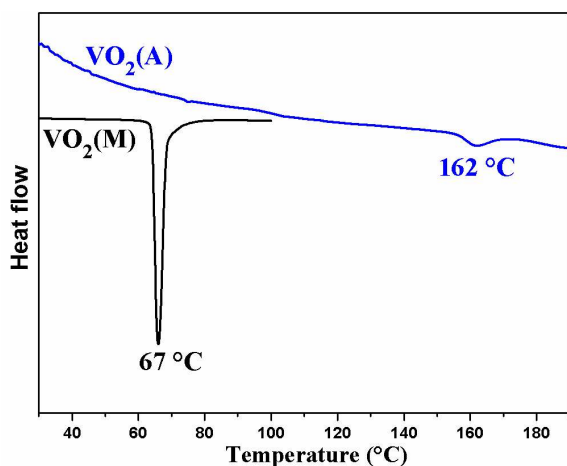


Fig. 7. DSC curves of the as-obtained VO₂(A) and VO₂(M) nanobelts.

According to the DSC results of the as-obtained VO₂(A) and VO₂(M), they reveal a noticeable endothermic peak in the heating cycle. It was reported that the optical properties have drastically changed when the reversible phase transition of VO₂(A) or VO₂(M) occurred. Therefore, we further developed the as-obtained VO₂(A) and VO₂(M) as the optical switching devices. The optical switching properties of VO₂(A) and VO₂(M) were investigated by variable-temperature infrared spectra, as shown in Fig. 8 and Fig. 9. It can be clearly seen from Fig. 8 that VO₂(A) has the optical switching properties at different vibratory absorption bands, revealing that it is a potential candidate for optical switching devices at the vibratory absorption bands from 700 to 650 cm⁻¹ and from 600 to 550 cm⁻¹. In case of VO₂(M), as shown in Fig. 9, it can be clearly observed that VO₂(M) has the optical switching properties. The optical transmission

below T_c is higher than that above T_c , suggesting that it has good thermochromic properties. Besides, it also reveals that VO₂(M) has potential applications in optical switching devices at the variety of vibratory absorption bands owing to its large transmission changes. These optical properties of VO₂(A) and VO₂(M) verify that they are beneficial for the development and application of optical switching materials.

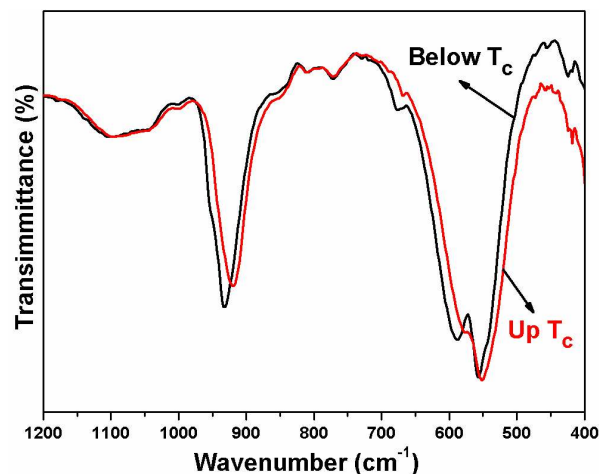


Fig. 8. Variable-temperature infrared spectra of VO₂(A) nanobelts below and above T_c .

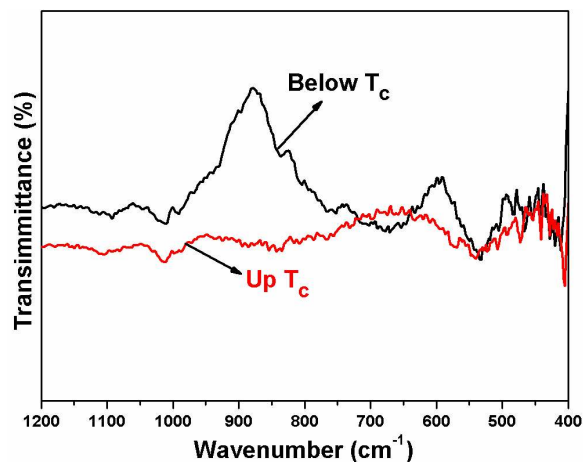


Fig. 9. Variable-temperature infrared spectra of VO₂(M) nanobelts below and above T_c .

It has been reported [1, 25, 34, 37–40] that the optical spectra, usually explained as the

observed bands, are related to the electromagnetic resonance between incident photons (with a specific wavenumber) and variation of chemical bond polarization associated with a specific vibration mode. At low temperature ($T < T_c$) the electrons involved in the $V^{4+}-V^{4+}$ bonds between VO₆ octahedra are localized. However, these electrons are delocalized at high temperature ($T > T_c$). In the metal state ($T > T_c$), this delocalization involves a screening effect for the incident photons, which occurs at the surface of the sample [37]. As a result, no vibrational absorption bands can be observed. In this circumstance, the transmittance drastically decreases. The variable-temperature infrared spectra confirm the strong reversible metal-insulator phase transition at around T_c .

4. Conclusions

In conclusion, the oxidation resistance properties of VO₂(B), VO₂(A) and VO₂(M) nanobelts were comparatively studied by TGA/DTA test. It was found that VO₂(B), VO₂(A) and VO₂(M) nanobelts had good thermal stability and oxidation resistance below 341 °C, 408 °C and 465 °C in air, respectively, and the fierce oxidation of the VO₂(B), VO₂(A) and VO₂(M) nanobelts occurred at 426, 507 and 645 °C, respectively. The results showed that VO₂(B), VO₂(A) and VO₂(M) nanobelts were stable in air at room temperature. VO₂(M) nanobelts had the best thermal stability and oxidation resistance, which was beneficial for the application of VO₂(M) in air. The T_c of VO₂(A) and VO₂(M) were about 162 °C and 67 °C, respectively. The optical switching properties of VO₂(A) and VO₂(M) were studied by the variable-temperature infrared spectra, which suggested that they can be used as the optical switching materials.

Acknowledgements

This work was partially supported by the Fundamental Research Funds for the Central Universities (DUT13RC(3)62) and the Science Research Project of the Liaoning Province Education Department (L2015123).

References

- [1] ZHANG Y., ZHANG J., ZHANG X., MO S., WU W., NIU F., ZHONG Y., LIU X., HUANG C., LIU X., *J. Alloys Compd.*, 570 (2013), 104.
- [2] ZHANG Y., WANG N., HUANG Y., HUANG C., MEI X., MENG C., *Mater Sci.-Poland*, 32 (2014), 236.
- [3] STRELCOV E., LILACH Y., KOLMAKOV A., *Nano Lett.*, 9 (2009), 2322.
- [4] ZHANG Y., FAN M., LIU X., HUANG C., LI H., *Eur. J. Inorg. Chem.*, 2012 (2012), 1650.
- [5] ZHANG Y., FAN M., WU W., HU L., ZHANG J., MAO Y., HUANG C., LIU X., *Mater. Lett.*, 71 (2012), 127.
- [6] PARKIN I.P., MANNING T.D., *J. Chem. Educ.*, 83 (2006), 393.
- [7] ZHANG Y., LIU X., CHEN D., YU L., NIE J., YI S., LI H., HUANG C., *J. Alloy. Compd.*, 509 (2011), L69.
- [8] ZHANG Y., ZHOU M., FAN M., HUANG C., CHEN C., CAO Y., LI H., LIU X., *Curr. Appl. Phys.*, 11 (2011), 1159.
- [9] ZHANG Y., HUANG C., MENG C., *Mater. Express*, 5 (2015), 105.
- [10] ZHANG Y., WANG N., HUANG Y., WU W., HUANG C., MENG C., *Ceram. Inter.*, 40 (2014), 11393.
- [11] WANG N., ZHANG Y., HU T., ZHAO Y., MENG C., *Curr. Appl. Phys.*, 15 (2015), 493.
- [12] KUMAR S., PICKETT M.D., STRACHAN J.P., GIBSON G., NISHI Y., WILLIAMS R.S., *Adv. Mater.*, 25 (42) (2013), 6128.
- [13] WU C.Z., XIE Y., *Energ. Environ. Sci.*, 3 (2010), 1191.
- [14] ZHANG Y., ZHANG X., HUANG Y., XIAO M., NIU F., HUANG C., MENG C., WU W., *Chem. Lett.*, 43 (3) (2014), 337.
- [15] ZHANG Y., LIU X., XIE G., YU L., YI S., HU M., HUANG C., *Mater. Sci. Eng. B*, 175 (2010), 164.
- [16] NGUYEN T.-D., DO T.-O., *Langmuir*, 25 (2009), 5322.
- [17] THEOBALD F., CABALA R., BERNARD J., *J. Solid State Chem.*, 17 (1976), 431.
- [18] ANDERSSON G., *Acta Chem. Scand.*, 10 (1956), 623.
- [19] WESTMAN S., *Acta Chem. Scand.*, 15 (1961), 217.
- [20] OKA Y., SATO S., YAO T., YAMAMOTO N., *J. Solid State Chem.*, 141 (1998), 594.
- [21] NI J.A., JIANG W.T., YU K., GAO Y.F., ZHU Z.Q., *Electrochim. Acta*, 56 (2011), 2122.
- [22] ZHANG Y., CHEN C., WU W., NIU F., LIU X., ZHONG Y., CAO Y., LIU X., HUANG C., *Ceram. Int.*, 39 (2013), 129.
- [23] MORIN F.J., *Phys. Rev. Lett.*, 3 (1959), 34.
- [24] GOODENOUGH J.B., *J. Solid State Chem.*, 3 (1971), 490.
- [25] ZHANG Y., FAN M., NIU F., WU W., HUANG C., LIU X., LI H., LIU X., *Curr. Appl. Phys.*, 12 (2012), 875.
- [26] ZHANG Y., HUANG Y., ZHANG J., WU W., NIU F., ZHONG Y., LIU X., LIU X., HUANG C., *Mater. Res. Bull.*, 47 (2012), 1978.
- [27] ZHANG Y., ZHANG X., HUANG Y., HUANG C., NIU F., MENG C., TAN X., *Solid State Commun.*, 180 (2014), 24.
- [28] ZYLBERSTEIN A., MOTT N.F., *Phys. Rev. B*, 11 (1975), 4383.

- [29] WHITTAKER L., WU T.L., PATRIDGE C.J., SAMBANDAMURTHY G., BANERJEE S., *J. Mater. Chem.*, 21 (2011), 5580.
- [30] ZHANG Y., ZHANG J., ZHANG X., HUANG C., ZHONG Y., DENG Y., *Mater. Lett.*, 92 (2013), 61.
- [31] JI S.D., ZHANG F., JIN P., *Mater. Lett.*, 65 (2011), 708.
- [32] SON J.H., WEI J., COBDEN D., CAO G.Z., XIA Y.N., *Chem. Mater.*, 22 (2010), 3043.
- [33] ZHANG S., SHANG B., YANG J., YAN W., WEI S., XIE Y., *Phys. Chem. Chem. Phys.*, 13 (2011), 15873.
- [34] ZHANG Y., FAN M., NIU F., ZHONG Y., HUANG C., LIU X., WANG B., LI H., *Micro Nano Lett.*, 6 (2011), 888.
- [35] ZHANG Y., LI W., FAN M., ZHANG F., ZHANG J., LIU X., ZHANG H., HUANG C., LI H., *J. Alloy. Compd.*, 544 (2012), 30.
- [36] OKA Y., YAO T., YAMAMOTO N., *J. Solid State Chem.*, 86 (1990), 116.
- [37] GUINETON F., SAUQUES L., VALMALETTE J.C., CROS F., GAVARRI J.R., *J. Phys. Chem. Solids*, 62 (2001), 1229.
- [38] RICHARDSON M.A., COATH J.A., *Opt. Laser Technol.*, 30 (1998), 137.
- [39] CONTINENZA A., MASSIDDA S., POSTERNAK M., *Phys. Rev. B*, 60 (1999), 15699.
- [40] ZHANG Y., FAN M., LIU X., XIE G., LI H., HUANG C., *Solid State Commun.*, 152 (2012), 253.

Received 2015-10-01

Accepted 2015-12-12